

Supporting Information

Effects of Layer Stacking on the Combination Raman Modes in Graphene

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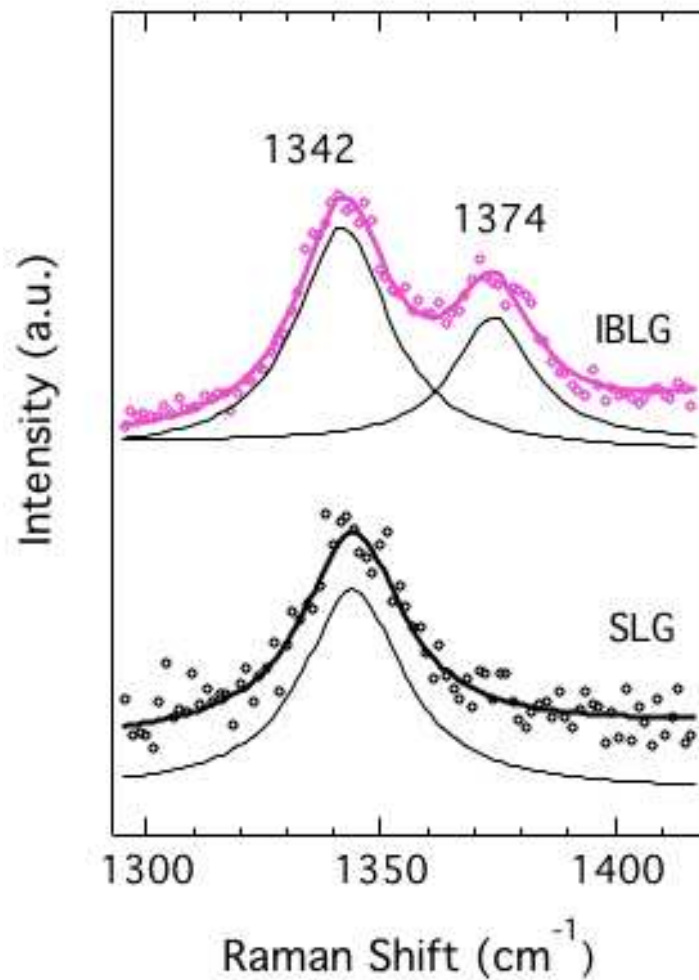


Figure S1.
spectra in the
region from
SLG. The
normalized by
of the G band.

Raman
D band
IBLG and
spectra were
the intensity

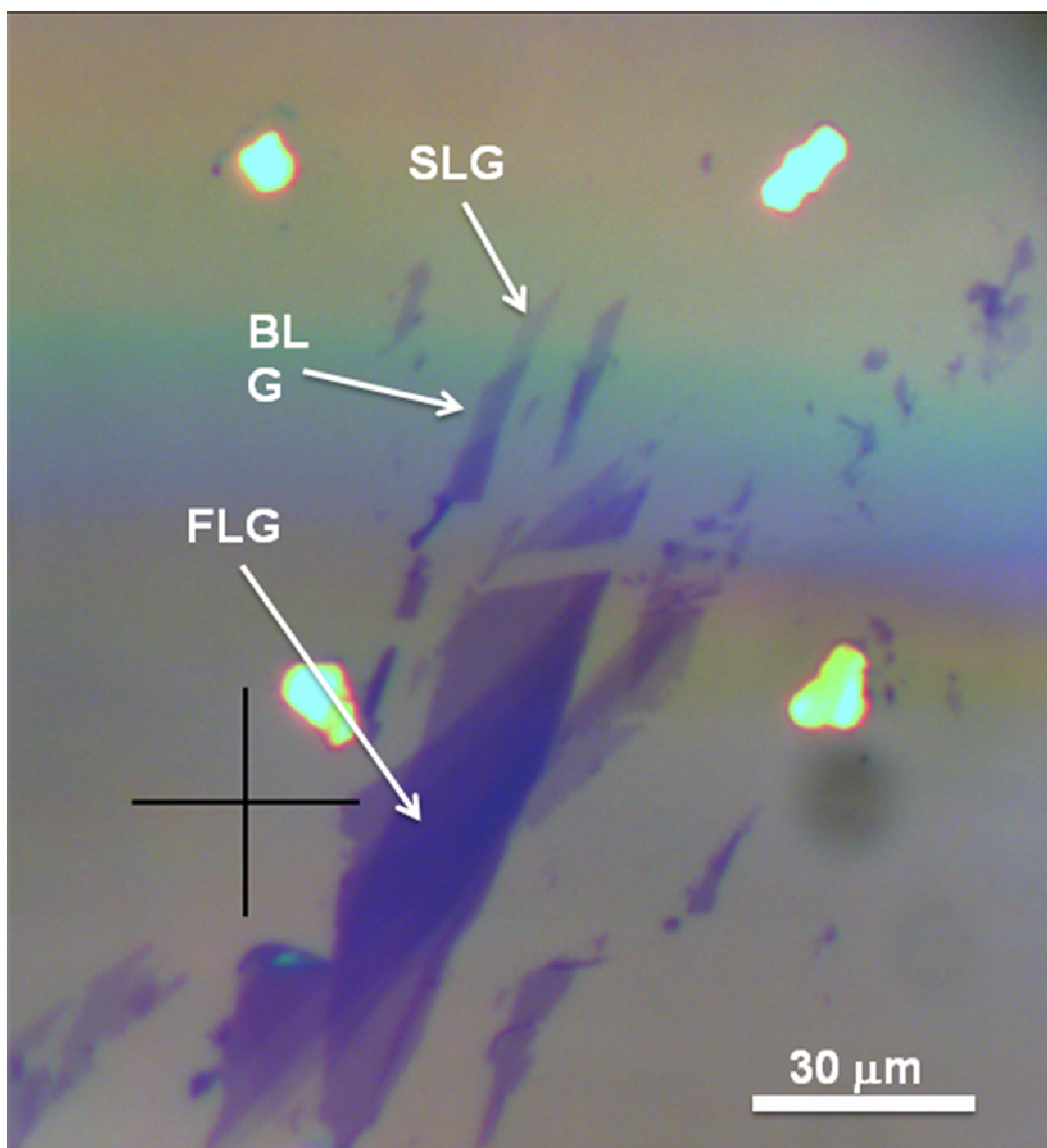
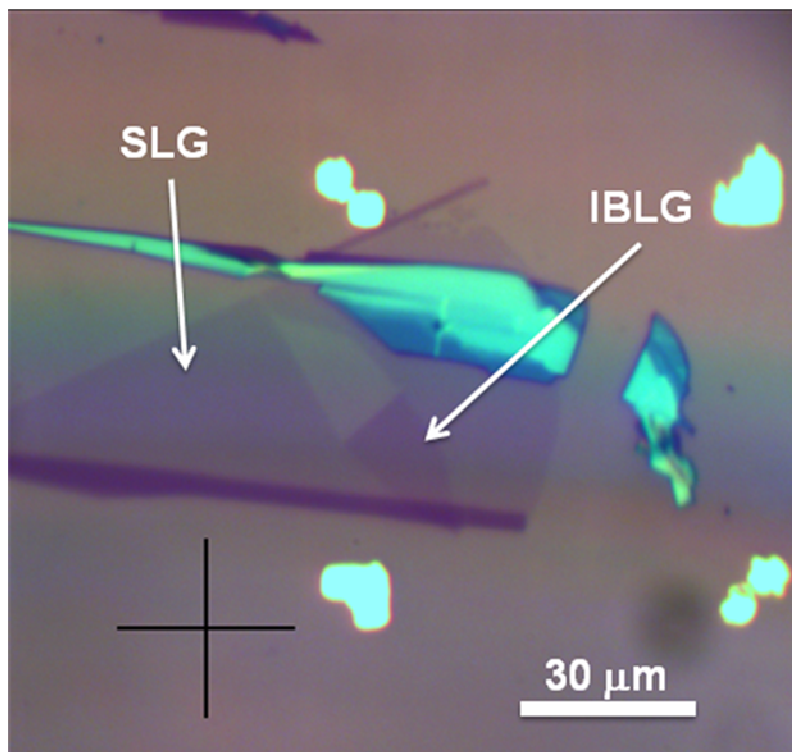


Figure S2 – Optical microscope (50 x magnification) image of graphene flakes having 1, 2, and few layer graphene on 280 nm SiO₂/Si substrate.

Figure S3 –
microscope



Optical
(50 x

magnification) image of a single layer graphene flake, a part of which has folded upon itself to form incommensurate bilayer graphene.